NSN 5961-01-219-3654

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-219-3654 **Inclosure Material:** Metal **Overall Length:** 1.820 inches **Overall Height:** 1.170 inches **Overall Width:** 0.510 inches **Mounting Facility Quantity: Component Name And Quantity:** 5 transistor **Mounting Method: Bracket Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 10 unthreaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0